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SEMICONDUCTOR

## 2SA1943/FJL4215 **PNP Epitaxial Silicon Transistor**

#### **Applications**

- High-Fidelity Audio Output Amplifier
- General Purpose Power Amplifier

#### Features

- High Current Capability:  $I_C = -17A$ .
- High Power Dissipation : 150watts.
- High Frequency : 30MHz. ٠
- High Voltage : V<sub>CEO</sub>= -250V •
- Wide S.O.A for reliable operation.
- Excellent Gain Linearity for low THD.
- Complement to 2SC5200/FJL4315.
- Full thermal and electrical Spice models are available.
- · Same transistor is also available in:
  - -- TO3P package, 2SA1962/FJA4213 : 130 watts
  - -- TO220 package, FJP1943 : 80 watts
  - -- TO220F package, FJPF1943 : 50 watts

#### Absolute Maximum Ratings\* T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
BV <sub>CBO</sub>	Collector-Base Voltage	-250	V	
BV <sub>CEO</sub>	Collector-Emitter Voltage	-250	V	
BV <sub>EBO</sub>	Emitter-Base Voltage	-5	V	
I <sub>C</sub>	Collector Current	-17	А	
I <sub>B</sub>	Base Current	-1.5	А	
P <sub>D</sub>	Total Device Dissipation(T <sub>C</sub> =25°C) Derate above 25°C	150 1.04	W W/°C	
T <sub>J</sub> , T <sub>STG</sub>	Junction and Storage Temperature	- 50 ~ +150	°C	

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### Thermal Characteristics\* T<sub>a=25°C</sub> unless otherwise noted

Symbol	Parameter	Max.	Units	
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	0.83	°C/W	

\* Device mounted on minimum pad size

#### h<sub>FE</sub> Classification

Classification	R	0	
h <sub>FE1</sub>	55 ~ 110	80 ~ 160	



January 2009

2SA1943/FJL4215 — PNP Epitaxial Silicon Transistor

1.Base 2.Collector 3.Emitter

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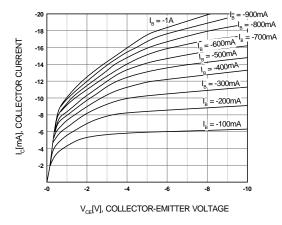
Electrical Characteristics* T <sub>a</sub> =25°C unless otherwise noted						
Symbol	Parameter	Parameter Test Condition		Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =-5mA, I <sub>E</sub> =0	-250			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C$ =-10mA, $R_{BE}$ = $\infty$	-250			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =-5mA, I <sub>C</sub> =0	-5			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =-230V, I <sub>E</sub> =0			-5.0	μA
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> =-5V, I <sub>C</sub> =0			-5.0	μA
h <sub>FE1</sub>	DC Current Gain	V <sub>CE</sub> =-5V, I <sub>C</sub> =-1A	55		160	
h <sub>FE2</sub>	DC Current Gain	V <sub>CE</sub> =-5V, I <sub>C</sub> =-7A	35	60		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =-8A, I <sub>B</sub> =-0.8A		-0.4	-3.0	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	V <sub>CE</sub> =-5V, I <sub>C</sub> =-7A		-1.0	-1.5	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =-5V, I <sub>C</sub> =-1A		30		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =-10V, f=1MHz		360		pF

\* Pulse Test: Pulse Width=20µs, Duty Cycle≤2%

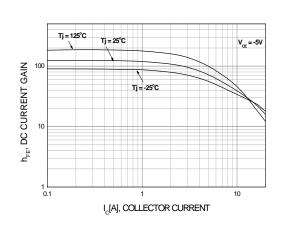
## **Ordering Information**

Part Number	Marking	Package	Packing Method	Remarks
2SA1943RTU	A1943R	TO-264	TUBE	hFE1 R grade
2SA1943OTU	A1943O	TO-264	TUBE	hFE1 O grade
FJL4215RTU	J4215R	TO-264	TUBE	hFE1 R grade
FJL4215OTU	J4215O	TO-264	TUBE	hFE1 O grade

## **Typical Characteristics**









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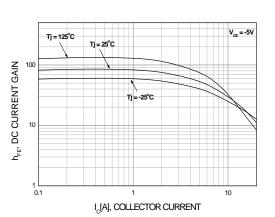
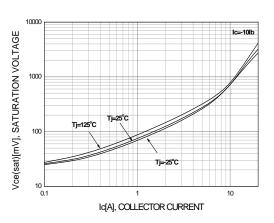
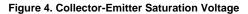
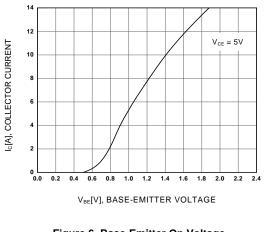


Figure 2. DC current Gain ( R Grade )









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## **Typical Characteristics**

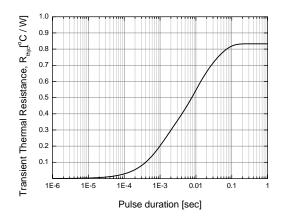
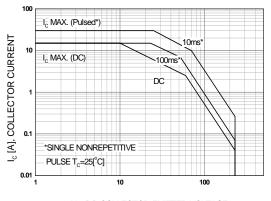


Figure 7. Thermal Resistance



 $\mathsf{V}_{\mathsf{CE}}\left[\mathsf{V}\right]\!,$  COLLECTOR-EMITTER VOLTAGE

Figure 8. Safe Operating Area

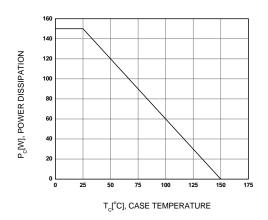
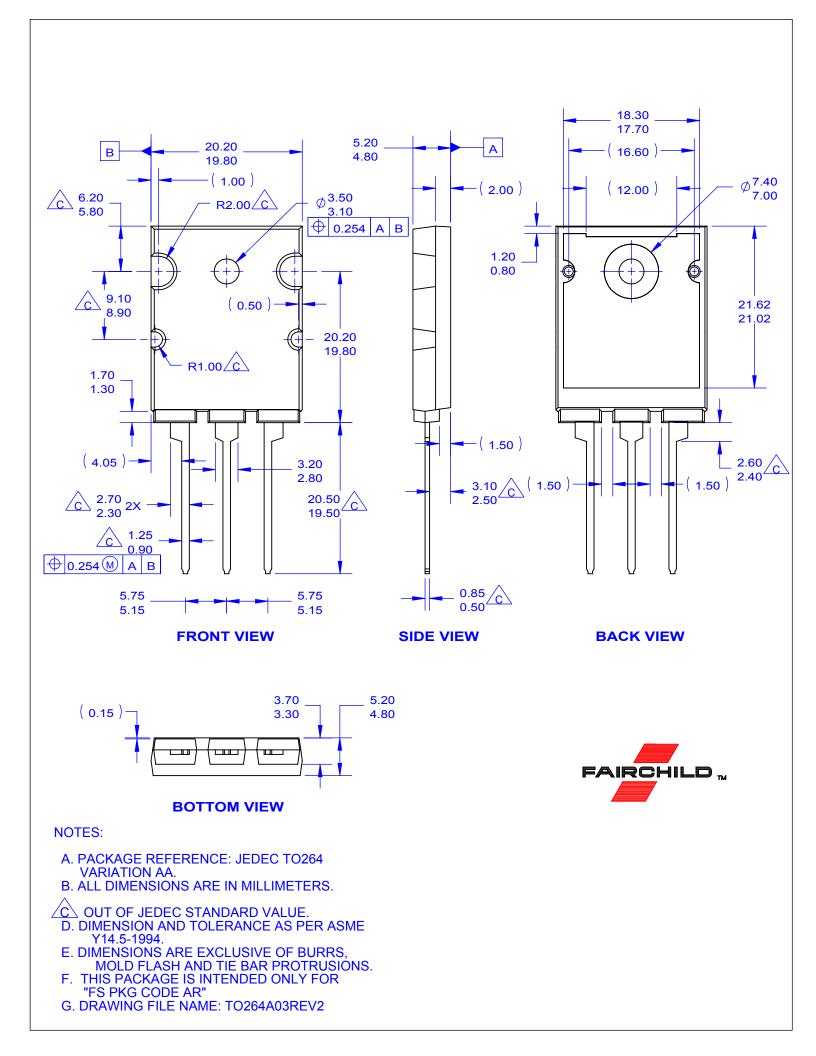


Figure 9. Power Derating

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